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Trisulfur radical anion-triggered stitching thienannulation: rapid access to largely π -extended thienoacenes†

Feng Su,^a Shuqi Chen,^a Xiaogang Mo,^a Kongchuan Wu,^a Jiajun Wu,^a Weidong Lin,^a Zhiwei Lin,^a Jianbin Lin, ^b ^{ab} Hui-Jun Zhang ^b ^{*} and Ting-Bin Wen ^a

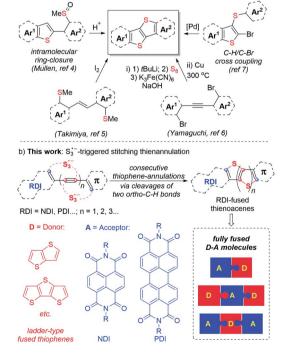
Largely π -extended rylene diimide-fused thienoacenes, a new family of fully fused electron donor-acceptor (D-A) molecules, have been readily synthesized by a novel trisulfur radical anion (S₃*-)-triggered stitching thienannulation strategy. The ladder-type fused thiophene cores are constructed in a stitching manner through multiple carbon-sulfur bond formation between acetylenic rylene dyes and S₃*-. A detailed mechanistic study of these stitching thienannulations unveiled the multiple reactivities of S₃*-. Physical properties of the newly formed D-A, A-D-A, and D-A-D type thienoacenes have also been investigated, which revealed their precisely controllable electronic properties.

Introduction

Largely π -extended thienoacenes, diacene-fused thienothiophenes such as [1]benzothieno[3,2-b][1] benzo-thiophene (BTBT) and related compounds constitute a useful class of molecules in the field of organic semiconducting materials due to their rigid planar conformation, well delocalized π -conjugation, unique intermolecular sulfur-sulfur interactions, and improved air stability compared with large acenes.^{1,2} To date, four reliable annulation approaches toward these skeletons have been reported (Scheme 1a).1e,f,3-8 However, each of these methods require the use of uncommon ortho-bifunctionalized aromatics as cyclization precursors, which means the options available to access such skeletons are rather limited. In addition, rylene diimides (RDIs) such as naphthalene diimides (NDIs) and perylene diimides (PDIs) represent an important class of n-channel organic semiconductors. Effective π -extensions of the NDI and PDI units are recognized as valuable approaches toward new molecular materials with precisely controlled electronic properties.9 In this context, fusion of electron-deficient RDI units (acceptors, A) and electron-rich thieno[3,2-b]thiophene or other ladder-type fused thiophenes (donors, D) may afford a variety of n-channel, p-channel, and ambipolar materials, depending on their specific electronic

The trisulfur radical anion $(S_3^{\bullet,-})$, as a ubiquitous sulfurcentered radical, has only recently received increasing attention in synthetic chemistry.^{11,12} Until now, exploration of its

a) Four annulation routes toward diacene-fused thienothiophenes



Scheme 1 Four annulation routes toward diacene-fused thienothiophenes (previous work) and S_3 --triggered stitching thienannulation (this work).

structures. 76,10 As a result, general and efficient synthetic pathways toward these appealing structures are highly desirable.

^aDepartment of Chemistry, College of Chemistry and Chemical Engineering, Xiamen University, Xiamen 361005, Fujian, P. R. China. E-mail: meghjzhang@xmu.edu.cn

^bMOE Key Laboratory of Spectrochemical Analysis and Instrumentation, Xiamen University, Xiamen 361005, P. R. China

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unique and multiple reactivities and application in the synthesis of useful organosulfur compounds remain limited. Conventionally, intermolecular reactions of normal sulfurcentered radicals, such as thiyl radicals (RS*) and sulfonyl radicals (RSO2'), with alkynes predominantly led to the formation of S-functionalized alkene derivatives.¹³ In contrast, herein, we discovered that S3. could initiate consecutive thiophene-annulations (stitching thienannulation) of arylacetylenic RDIs via cleavage of two ortho-C-H bonds to afford a host of rylene diimide-fused largely π -extended soluble thienoacenes (Scheme 1b). With controllable electronic structures (D-A type, D-A-D type and A-D-A type), these RDI-fused thienoacenes are for high-performance candidates semiconductors.14

Results and discussion

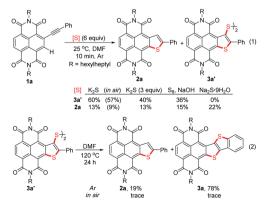
Stitching thienannulation of phenylethynyl substituted RDIs

In recent years, Takimiya et al.,15 Wang et al.16 and our group17 have discovered that alkynyl-substituted rylene dves could undergo direct thiophene-annulation reactions (thienannulations) with Na2S, S8 or K2S to form important thiophenefused RDIs. Initially, to gain insight into the mechanisms of these thienannulation processes, the reaction of simple phenylethynyl substituted NDI 1a with different sulfur reagents at room temperature was studied (Scheme 2, eqn (1)). To our surprise, with addition of 6 equiv. of K2S in N,N-dimethylformamide (DMF) solution, 1a was entirely consumed within 10 min and afforded not only a normal thienannulation product 2a in 13% yield but also an abnormal disulfide product 3a' in 60% yield (Scheme 2, eqn (1)).18 The reaction also took place in air and afforded similar results (2a, 9%; 3a', 57%). Reducing the amount of K₂S to 3 equiv. led to the formation of 3a' in a lower yield (40%). Treatment of 1a with S₈ in the presence of NaOH also produced 2a and 3a' in 15% and 36% yields, respectively. Previously, Na₂S·9H₂O has been recognized as an efficient sulfur source for thienannulation of bis(trimethylsilyl)ethynyl substituted NDI to yield naphtho [2,3-b:6,7-b']dithiophene diimide (NDTI). 15,16a Nonetheless, the reaction of 1a with 6 equiv. of Na₂S·9H₂O at room temperature furnished only 2a in 22% yield. 38% of 1a was recovered, and

disulfide product 3a' was not formed at all. Realizing that S₃'-can be generated from the DMF solution of K₂S and the DMF solution of a mixture of elemental sulfur and NaOH at room temperature, ^{12a,c} we explored whether S₃'- was responsible for this unique thienannulation process. UV-visible spectra of K₂S, S₈/NaOH and Na₂S·9H₂O in DMF were all recorded at room temperature (Fig. 1). A characteristic absorption peak of S₃'- at 617 nm (ref. 11) have been found for the DMF solutions of K₂S and S₈/NaOH. Clearly, the yields of 3a' in the reactions are close related to the concentrations of S₃'- in the solutions, indicating that S₃'- was most likely involved in this reaction process.

More interestingly, later we found that 3a' could further undergo a direct thienannulation at 120 °C, without the addition of any transition-metal catalysts and additional oxidants, ¹⁹ producing an NDI-fused thienoacene product 3a in 78% yield, accompanied by 2a in 19% yield (Scheme 2, eqn (2)). Notably, performing this reaction in air was detrimental and 70% of 3a' was recovered after the reaction.

Motivated by these results, we expected to construct 3a directly from 1a via a one-pot consecutive thienannulation (stitching thienannulation) process (Table 1). To our delight, direct treatment of 1a with 6 equiv. of K2S at 120 °C for 24 h indeed furnished 3a in 51% yield (entry 1). Higher temperature was found to increase the yield of 3a to 66% (entry 2). As the amount of K₂S was reduced, the yield of 3a was decreased, while the yield of 2a was dramatically increased (entries 3 and 4). Addition of 30 equiv. of H₂O in the reaction had almost no adverse effects on the stitching thienannulation process (entry 5). Other sulfur reagents, such as Na₂S·9H₂O and S₈, were also employed as sulfur sources for the synthesis of 3a albeit with much lower yields (entries 6 and 7). When the reaction between 1a and S₈ was performed in the presence of 10 equiv. of Et₃N, 2a was selectively formed in 98% yield (entry 8). Note that the yields of 3a in these reactions are also close related to the concentrations of S₃. in the DMF solutions (see Fig. S1†).20 Gratifyingly, performing the reaction of 1a with 6 equiv. of K₂S at 25 °C for 10 min and then at 140 °C for 24 h led to the formation of 3a in 83% yield (entry 9). This is obviously the fastest way to produce diarene-fused thienothiophenes (Scheme 1a).



Scheme 2 Thienannulations of 1a and 3a'.

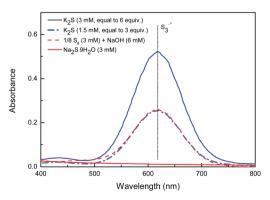


Fig. 1 UV-visible spectra of K₂S, S₈/NaOH and Na₂S·9H₂O in DMF.

Table 1 Optimization of reaction conditions^a

Entry	Reaction conditions (reagent (equiv))	% Yield of $3a^b$	% Yield of $2a^b$
1	K ₂ S (6), 120 °C	51	19
2	K ₂ S (6), 140 °C	66	16
3	K ₂ S (4), 140 °C	42	44
4	K ₂ S (2), 140 °C	10	64
5 ^c	K ₂ S (6), H ₂ O (30), 140 °C	60	19
6	$Na_2S \cdot 9H_2O$ (6), 140 °C	20	15
7	S ₈ (6), 140 °C	10	71
8	S ₈ (6), Et ₃ N (10), 140 °C	Trace	98
9^d	K ₂ S (6), 140 °C	83	16

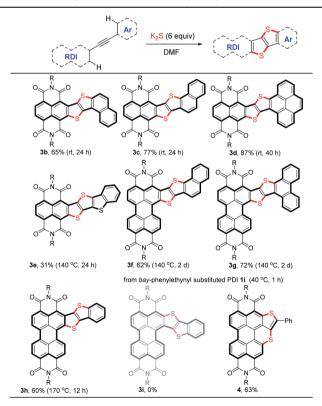
^a Reactions were run in 0.03 mmol scale for 24 h in Ar (R = hexylheptyl). ^b Isolated yields of **2a** and **3a**. ^c 40 h. ^d Before heating at 140 °C, the reaction mixture was stirred at 25 °C for 10 min.

Substrate scope

The scope of the double thienannulation was first examined with respect to four arylethynyl substituted NDIs 1b-e, three ortho-arylethynyl substituted PDIs 1f-h²¹ and one bay-phenylethynyl substituted PDI 1i (Table 2). The stitching thienannulations of (1-naphthyl)ethynyl-NDI 1b, (2-naphthyl)ethynyl-NDI 1c and (4-pyrenyl)ethynyl-NDI 1d, all polycyclic aromatic hydrocarbon (PAH) derivatives, proceeded smoothly even at room temperature and afforded the corresponding NDI-fused thienoacenes 3b-d in good yields (65-87%). The reaction between (2-benzothienyl)ethynyl substituted NDI 1e and K2S was performed at 140 °C and furnished 3e in 31% yield. Besides these acetylenic NDIs, acetylenic PDIs were also susceptible to this transformation. The reactions of (2-naphthyl)ethynyl-PDI 1f and (9-phenanthryl)ethynyl-PDI 1g with K2S were both carried out at 140 °C and afforded the corresponding PDI-fused thienoacenes 3f and 3g in 62% and 72% yields, respectively. Compared with the PAH derivatives 1f and 1g, less reactive ortho-phenylethynyl substituted PDI 1h underwent double thienannulations at a higher temperature (170 °C), affording the desired product 3h in 60% yield. In contrast, the reaction of bay-phenylethynyl substituted PDI 1i with K2S proceeded smoothly at 40 °C and furnished a thienobenzothiopyran product 4 in 63% yield. In this case, the desired PDI-fused thienoacene 3i was not formed perhaps due to the much higher reactivity of PDI unit compared with phenyl ring during the S₃. -triggered thienannulation.

Ladder-type heteroacenes with planar molecular backbones and zero conformational disorder are potentially promising candidates for many optoelectronic applications. ¹ Using the S₃. -triggered stitching thienannulation approach, two large

Table 2 Stitching thienannulations of arylacetylenic RDIs^{a,b}



 ^a Reactions were run in 0.03-0.05 mmol scale in Ar (R = hexylheptyl).
 ^b Isolated yields of 3 or 4 (reaction temperature and time are shown in parentheses).

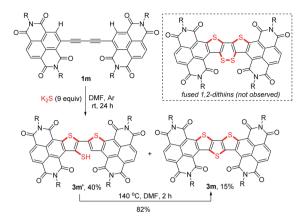
Scheme 3 Stitching thienannulations of 1j and 1k.

NDI-fused ladder-type thienoacenes 3**j** and 3**k** could be readily synthesized from the corresponding bisarylethynyl substituted NDI 1**j** and *p*-phenylenediyne-linked NDI dimer 1**k** in good yields (Scheme 3). Notably, during both of these two reactions, four *ortho-*C–H bonds in the starting compound were cleaved and functionalized in one-pot.

To further explore the potential applications of this stitching thie nannulation strategy, ethyne-, butadiyne-, and hexatriyne-bridged RDI dimers 1l–q were examined (Table 3). With appropriate amounts of K_2S , these oligoyne-tethered RDI dimers could directly undergo double, triple, or even quadruple thie nannulations to furnish the corresponding π -extended thie noacenes 3l–q. 22 The corresponding fused 1,2-dithiin products were not observed. $^{6\alpha}$

To figure out the detailed thienannulation process of oligoyne-bridged RDI dimers, both the reactions of butadiyne-bridged RDI dimer 1m and 1q with K_2S were carefully investigated at lower

Table 3 Stitching thienannulations of oligoyne-bridged RDI dimers



Scheme 4 Consecutive thienannulations of 1m.

temperatures (Scheme 4 and Table S4†). Treatment of **1m** with 9 equiv. of K_2S in DMF at room temperature afforded not only the triple thienannulation product **3m** in 15% yield, but also a double thienannulation product **3m'** in 40% yield (Scheme 4).²² Directly heating the DMF solution of **3m'** at 140 °C for 2 h produced **3m** in 82% yield. Similar reactions were also observed for **1q** (Table S4†), which provided insight into the selective formation of π -extended thienoacenes rather than fused 1,2-dithiins.

Further mechanistic studies

To gain a deeper insight into the mechanism of the stitching thienannulation process, we then conducted additional experiments. First, the key step involving the formation of $\bf 2a$ and $\bf 3a'$

a) Formation of
$$3a'$$
 in the presence of water

OH H2O (30 equiv)
H2O (30 equiv)
DMF, 25 °C
Ar, 10 min

R

1a

2a, 12%

DMF, 140 °C
Ar, 24 h

TEMPO adduct
49% isolated yield

c) Selective formation of $2a$

10 min

 $2a$ or $2a$ -D

 $2a$ or $2a$ -D

 $2a$ over $2a$ -D

 $2a$ or $2a$ -D

 $2a$ or $2a$ -D

 $2a$ or $2a$ -D

 $2a$ -D

 $2a$ -C

 $2a$

Scheme 5 Mechanistic studies on the thienannulation of 1a: (a) formation of 3a' in the presence of water, (b) radical-trapping experiments and (c) selective formation of 2a.

 $[^]a$ Reactions were run in 0.02–0.04 mmol scale in Ar (R = hexylheptyl). b Isolated yields of 3 (reaction temperatures and times are shown in parentheses).

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was investigated in detail (Scheme 5). For the reaction of 1a with 6 equiv. of K₂S at room temperature for 10 min, the presence of 30 equiv. of H₂O did not significantly affect the yields of 2a and 3a' (Scheme 5a). When 10 equiv. of TEMPO as radical scavenger was added, a TEMPO-adduct was formed instead of the disulfide 3a' (Scheme 5b, S2 and Fig. S7†). These results confirmed a radical mechanism. Later, directly heating the isolated TEMPO-adduct in DMF at 140 °C afforded the double thienannulation product 3a. Based on this result, we speculate that a labile sulfurated thiophene intermediate that could be easily oxidized during work-up in air to produce 3a' was formed in the reaction. During optimization of the reaction conditions (see Table S1†), we noticed that reducing the amount of K2S led to the formation of 3a' in lower yields. Other than that, as the reaction time increased, the yield of 3a' decreased, while the yield of 2a increased (for the reaction progresses monitored by UV-vis spectroscopy, see Fig. S5†). This changing trend of the yields is more evident for the reaction performed at a slightly higher temperature. For instance, although treatment of 1a with 3 equiv. of K₂S at 35 °C for 10 min predominantly produced 3a' in 36% yield, prolonging the reaction time to 24 h resulted in the selective formation of 2a in 73% yield (Scheme 5c). Thereafter, the latter transformation was further investigated with a deuteration experiment (Scheme 5c). When adding 10 equiv. of D₂O in the reaction, 2a-D was isolated in 67% yield with 53% deuterium incorporation at the β-position of the thiophene ring. These results indicate that the labile sulfurated thiophene intermediate can be slowly decomposed in Ar to afford a thiophene anion intermediate which is protonated to afford 2a.23 Therefore, based on the substrate scope and the above results, we proposed that the stitching thienannulation should be initiated with the attack of S₃. on either alkyne or RDI unit and

Structural and physical properties of RDI-fused thienoacenes

a sulfurated thiophene intermediate is formed as a key inter-

mediate (see Scheme S3† for a plausible mechanism).

These newly formed D-A (3a-h), D-A-D (3j) and A-D-A (3k-q) type thienoacenes possess three major structural advantages in exploration of excellent organic semiconductors: (1) the conformational rigidity that allows them to have reduced reorganization energies and favorable intermolecular π - π stackings; (2) extended π -conjugation lengths and increased electron delocalization, leading to reduced bandgaps and broadened absorptions; and (3) strong dipole-dipole and sulfur-sulfur interactions which lead to ordered intermolecular arrangements. In addition, these molecules all have good solubilities in common organic solvents, such as CH₂Cl₂, CHCl₃, toluene and tetrahydrofuran, which is beneficial for solution processing. To gain a deeper insight into their photophysical properties, UV-vis absorption measurements of 3a-h and 3j-q were performed (Fig. S10-S12†). Compared with simple core-unsubstituted NDI, PDI and mono-thiophene-fused NDI 2a, these RDI-fused thienoacenes exhibited large bathochromic shifts in their UV-vis absorption spectra due to the extension of π -conjugation. Moreover, higher intensities of absorption peaks in the longwavelength region suggested a strong intramolecular charge

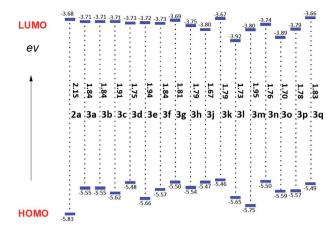


Fig. 2 Energy level diagram of RDI-fused thienoacenes **3a-h** and **3j-g**.

transfer in RDI-fused thienoacenes. Thereafter, the electrochemical properties of 3a-h and 3j-q were compared using cyclic voltammetry (Fig. 2, S13-S15 and Table S5†). Compared to 2a, eight D-A type thienoacenes 3a-h have similar reduction potentials, whereas their oxidation potentials are finely tuned by the variation of fused-thiophene-ring and conjugation length, indicating that the LUMOs tend to localize on the RDI skeleton and the HOMOs tend to delocalize in the lateral direction.15 Compared to these asymmetric fused D-A systems, symmetric D-A-D type thienoacene 3j has an obviously lower LUMO level, indicating its higher electron affinity. 7b For A-D-A type thienoacenes 3k-q, the HOMO and LUMO energy levels increase as the donor length increase because the large conjugation enhances the electron donating abilities, resulting in narrowed bandgaps. Moreover, compared to NDI fused A-D-A type thienoacenes, PDI fused counterparts have higher LUMO levels and exhibit more red-shifted UV-vis spectra. All these results suggested that the variation in the relative strengths of donor (ladder-type fused thiophene rings) and acceptor (RDI units), fused-ring number, and ring-fusion sequence in these D-A, D-A-D and A-D-A systems allowed finetuning of their absorption profiles, energy levels and charge-transport properties, which may eventually enable practical applications as organic semiconducting materials.

Conclusions

In conclusion, we have developed a novel S_3 .—triggered stitching thienannulation approach for the rapid construction of RDIfused, largely π -extended thienoacenes from ethyne-, butadiyne-, and hexatriyne-linked π -systems. With this facile and straightforward strategy, thieno[3,2-b]thiophene-, dithieno[3,2-b:2',3'-d]thiophene and tetrathienoacene substructures can be readily constructed in a stitching manner. Detailed mechanistic studies revealed the unique reactivity of S_3 .— and displayed the high reactivities of π -deficient RDI rings toward the radical thienannulation process. Furthermore, interesting properties including planar conformation, extended conjugation and precisely controllable electronic properties are integrated into

these novel fully fused electron donor-acceptor molecules, which are promising candidates for high performance organic semiconductors. These findings are anticipated to provide new opportunities to explore more general methods for the synthesis of useful organosulfur compounds.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

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Notes and references

- For reviews, see: (a) J. E. Anthony, Chem. Rev., 2006, 106, 5028; (b) K. Takimiya, S. Shinamura, I. Osaka and E. Miyazaki, Adv. Mater., 2011, 23, 4347; (c) C. Wang, H. Dong, W. Hu, Y. Liu and D. Zhu, Chem. Rev., 2012, 112, 2208; (d) W. Jiang, Y. Li and Z. Wang, Chem. Soc. Rev., 2013, 42, 6113; (e) M. E. Cinar and T. Ozturk, Chem. Rev., 2015, 115, 3036; (f) Z. Cai, M. A. Awais, N. Zhang and L. Yu, Chem, 2018, 4, 2538.
- 2 For selected examples, see: (a) K. Takimiya, H. Ebata, K. Sakamoto, T. Izawa, T. Otsubo and Y. Kunugi, J. Am. Chem. Soc., 2006, 128, 12604; (b) H. Ebata, T. Izawa, E. Miyazaki, K. Takimiya, M. Ikeda, H. Kuwabara and T. Yui, J. Am. Chem. Soc., 2007, 129, 15732; (c) K. Niimi, S. Shinamura, I. Osaka, E. Miyazaki and K. Takimiya, J. Am. Chem. Soc., 2011, 133, 8732; (d) A. Y. Amin, A. Khassanov, K. Reuter, T. Meyer-Friedrichsen and M. Halik, J. Am. Chem. Soc., 2012, 134, 16548; (e) Y. Miyata, E. Yoshikawa, T. Minari, K. Tsukagoshi and S. Yamaguchi, J. Mater. Chem., 2012, 22, 7715; (f) J. Huang, H. Luo, L. Wang, Y. Guo, W. Zhang, H. Chen, M. Zhu, Y. Liu and G. Yu, Org. Lett., 2012, 14, 3300; (g) T. Zheng, Z. Cai, R. Ho-Wu, S. H. Yau, V. Shaparov, T. Goodson III and L. Yu, J. Am. Chem. Soc., 2016, 138, 868.
- 3 For intramolecular ring closure of aromatic methyl sulfoxides, see: (a) H. Sirringhaus, R. H. Friend, C. Wang, J. Leuninger and K. Müllen, *J. Mater. Chem.*, 1999, **9**, 2095; (b) P. Gao, D. Beckmann, H. N. Tsao, X. Feng, V. Enkelmann, M. Baumgarten, W. Pisula and K. Müllen, *Adv. Mater.*, 2009, **21**, 213.
- 4 D. Cho, X. Yang, V. Enkelmann, M. Baumagarten and K. Müllen, *Chem.–Eur. J.*, 2010, **16**, 5119.
- 5 For iodine-promoted ring closure of stilbene derivatives, see: (a) T. Yamamoto and K. Takimiya, *J. Am. Chem. Soc.*, 2007, **129**, 2224; (b) T. Yamamoto, T. Nishimura, T. Mori,

- E. Miyazaki, I. Osaka and K. Takimiya, *Org. Lett.*, 2012, **14**, 4914.
- 6 For intramolecular multiple cyclizations of bis(3-bromo-2-thienyl)-acetylenes and bis(o-haloaryl)diacetylenes, see: (a)
 T. Okamoto, K. Kudoh, A. Wakamiya and S. Yamaguchi, Org. Lett., 2005, 7, 5301; (b) T. Okamoto, K. Kudoh, A. Wakamiya and S. Yamaguchi, Chem.-Eur. J., 2007, 13, 548.
- 7 For the construction of thieno[3,2-b]thiophene skeleton *via* Pd-catalyzed C-H/C-Br couplings, see: (a) T. Mori, T. Nishimura, T. Yamamoto, I. Doi, E. Miyazaki, I. Osaka and K. Takimiya, *J. Am. Chem. Soc.*, 2013, **135**, 13900; (b) J. Wen, C. Xiao, A. Lv, H. Hayashi and L. Zhang, *Chem. Commun.*, 2018, **54**, 5542.
- 8 For other methods toward linearly condensed thiophenes, see: (a) K. Xiao, Y. Liu, T. Qi, W. Zhang, F. Wang, J. Gao, W. Qiu, Y. Ma, G. Cui, S. Chen, X. Zhan, G. Yu, J. Qin, W. Hu and D. Zhu, *J. Am. Chem. Soc.*, 2005, 127, 13281; (b) X. Zhang, A. P. Côté and A. J. Matzger, *J. Am. Chem. Soc.*, 2005, 127, 10502; (c) L. Meng, T. Fujikawa, M. Kuwayama, Y. Segawa and K. Itami, *J. Am. Chem. Soc.*, 2016, 138, 10351.
- For reviews, see: (a) L. Chen, C. Li and K. Müllen, J. Mater. Chem. C, 2014, 2, 1938; (b) F. Würthner, C. R. Saha-Möller, B. Fimmel, S. Ogi, P. Leowanawat and D. Schmidt, Chem. Rev., 2016, 116, 962; (c) C. Li, Z. Lin, Y. Li and Z. Wang, Chem. Rec., 2016, 16, 873; (d) H. Zhylitskaya and M. Stępień, Org. Chem. Front., 2018, 5, 2395; (e) A. Nowak-Król and F. Würthner, Org. Chem. Front., 2019, 6, 1272.
- 10 (a) P. E. Hartnett, H. S. S. R. Matte, N. D. Eastham,
 N. E. Jackson, Y. Wu, L. X. Chen, M. A. Ratner,
 R. P. H. Chang, M. C. Hersam, M. R. Wasielewski and
 T. J. Marks, Chem. Sci., 2016, 7, 3543; (b) Z. Cai,
 R. J. Vázquez, D. Zhao, L. Li, W.-y. Lo, N. Zhang, Q. Wu,
 B. Keller, A. Eshun, N. Abeyasing, H. Banaszak-Holl,
 T. Goodson III and L. Yu, Chem. Mater., 2017, 29, 6726.
- 11 T. Chivers and P. J. W. Elder, Chem. Soc. Rev., 2013, 42, 5996.
- 12 (a) G. Zhang, H. Yi, H. Chen, C. Bian, C. Liu and A. Lei, Org. Lett., 2014, 16, 6156; (b) W. Liu, C. Chen and H. Liu, Adv. Synth. Catal., 2015, 357, 4050; (c) Z.-Y. Gu, J.-J. Cao, S.-Y. Wang and S.-J. Ji, Chem. Sci., 2016, 7, 4067; (d) J.-H. Li, Q. Huang, S.-Y. Wang and S.-J. Ji, Org. Lett., 2018, 20, 4704; (e) L. Chen, H. Min, W. Zeng, X. Zhu, Y. Liang, G. Deng and Y. Yang, Org. Lett., 2018, 20, 7392.
- 13 (a) U. Wille, Chem. Rev., 2013, 113, 813; (b) W. Guo, K. Tao, W. Tan, M. Zhao, L. Zheng and X. Fan, Org. Chem. Front., 2019, 6, 2048.
- 14 (a) H. Dong, X. Fu, J. Liu, Z. Wang and W. Hu, Adv. Mater., 2013, 25, 6158; (b) X. Gao and Z. Zhao, Sci. China: Chem., 2015, 58, 947.
- 15 (a) Y. Fukutomi, M. Nakano, J.-Y. Hu, I. Osaka and K. Takimiya, J. Am. Chem. Soc., 2013, 135, 11445; (b)
 W. Chen, M. Nakano, J.-H. Kim, K. Takimiya and Q. Zhang, J. Mater. Chem. C, 2016, 4, 8879; (c) M. Nakano and K. Takimiya, Chem. Mater., 2017, 29, 256; (d)
 K. Takimiya and M. Nakano, Bull. Chem. Soc. Jpn., 2018, 21, 121
- 16 (a) W. Fan, C. Liu, Y. Li and Z. Wang, *Chem. Commun.*, 2017, 53, 188; (b) C. Zeng, C. Xiao, X. Feng, L. Zhang, W. Jiang and

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Z. Wang, *Angew. Chem., Int. Ed.*, 2018, **57**, 10933; (c) C. Zeng, D. Meng, W. Jiang and Z. Wang, *Org. Lett.*, 2018, **20**, 6606.

- 17 J. Wu, D. He, Y. Wang, F. Su, Z. Guo, J. Lin and H.-J. Zhang, *Org. Lett.*, 2018, **20**, 6117.
- 18 Before product isolation, the reaction mixture should be stirred in air for 1 h. Otherwise, three thienannulation products (2a, 3a' and thiol 3a'') could be formed. For details, see the ESI.†
- 19 For classical synthesis of dibenzothiophenes from 2-biphenylthiols or 2-biphenylyl disulfides, see: (a) T. Zhang, G. Deng, H. Li, B. Liu, Q. Tan and B. Xu, *Org. Lett.*, 2018, **20**, 5439; (b) K. Nishino, Y. Ogiwara and N. Sakai, *Chem.–Eur. J.*, 2018, **24**, 10971; (c) K. Nishino, Y. Ogiwara and N. Sakai, *Eur. J. Org. Chem.*, 2017, 5892.
- 20 For UV-visible spectra studies of several sulfur reagents, please see Fig. S1.†
- 21 (a) J. Wu, D. He, L. Zhang, Y. Liu, X. Mo, J. Lin and H.-J. Zhang, Org. Lett., 2017, 19, 5438; (b) F. Su, G. Chen, P. A. Korevaar, F. Pan, H. Liu, Z. Guo, A. P. H. J. Schenning, H.-J. Zhang, J. Lin and Y.-B. Jiang, Angew. Chem., Int. Ed., 2019, 58, 15273.
- 22 The structures of **3l**, **3m** and **3m**' were all confirmed by single-crystal X-ray diffraction analysis (Fig. S3 and S9†).
- 23 Note that **2a** can also be formed through a direct addition of sulfide anion to the ethyne moiety followed by a subsequent intramolecular cyclization (see entry 9 in Table S1† and Fig. 1).